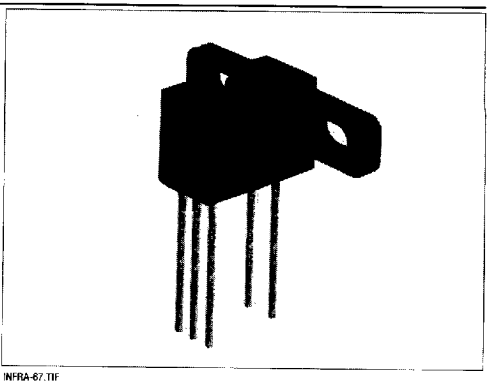
HOA2004

Transmissive Optoschmitt Sensor

FEATURES

- Direct TTL interface
- Buffer logic
- Side mount package
- 0.125 in.(3.18 mm) slot width



INFRA-67.TIF

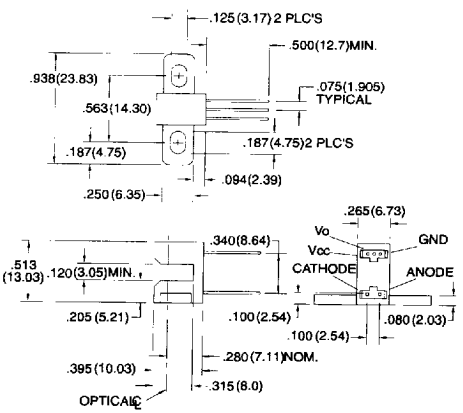
DESCRIPTION

The HOA2004 consists of an infrared emitting diode facing an Optoschmitt detector encased in a black thermoplastic housing. The photodetector consists of a photodiode, amplifier, voltage regulator, Schmitt trigger and an NPN output transistor with 10 kΩ (nominal) pull-up resistor. The buffer logic provides a high output when the optical path is clear, and a low output when the path is interrupted. The side mounting package is useful in applications in which the interruptive element is parallel to the mounting plane. Both emitter and detector have a 0.020 in.(.508 mm) x 0.040 in.(1.02 mm) vertical aperture. The narrow aperture is ideal for use in applications in which maximum position resolution is desired. The HOA2004 employs plastic molded components. For additional component information see SEP8506 and SDP8600.

Housing material is polyester. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

OUTLINE DIMENSIONS in inches (mm)

Tolerance	3 plc decimals	±0.010(0.25)
	2 plc decimals	±0.020(0.51)



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Transmissive Optoschmitt Sensor

ELECTRICAL CHARACTERISTIC (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	V_F			1.6	V	I_F=20 mA
Reverse Leakage Current	I_R			10	µA	V_R=3 V
DETECTOR						
Operating Supply Voltage	V_{CC}	4.5		12	V	
Low Level Supply Current	I_{CCL}	4.0		12	mA	V_{CC}=5 V
		5.0		15		V_{CC}=12 V
High Level Supply Current	I_{CCH}	2.0		10	mA	V_{CC}=5 V
		3.0		12		V_{CC}=12 V
Low Level Output Voltage	V_{OL}			0.4	V	I_{OL}=12.8 mA, I_F=0 mA
High Level Output Voltage	V_{OH}	2.4			V	I_{OH}=0, I_F=20 mA
Hysteresis (2)	HYST		10		%	
Propagation Delay, Low-High	t_{PLH}		5		µs	V_{CC}=5 V, I_F=20 mA
Propagation Delay, High-Low	t_{PHL}		5		µs	V_{CC}=5 V, I_F=20 mA
Rise Time	t_r		60		ns	R_L=390 Ω, C_L=50 pF
Fall Time	t_f		15		ns	R_L=390 Ω, C_L=50 pF
COUPLED CHARACTERISTICS						
IRED Trigger Current	I_{FT}				mA	V_{CC}=5 V
HOA2004-001				20		

Notes
1. It is recommended that a bypass capacitor, 0.1 µF typical, be added between V_{CC} and GND near the device in order to stabilize power supply line.
2. Hysteresis is defined as the difference between the operating and release threshold intensities, expressed as a percentage of the operate threshold intensity.

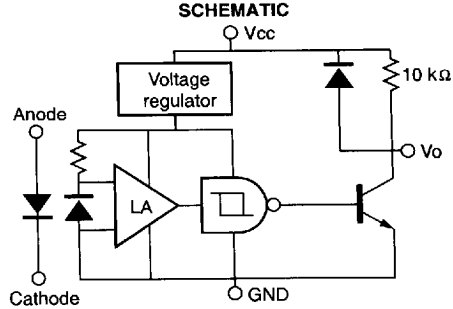
ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range	-40°C to 70°C
Storage Temperature Range	-40°C to 85°C
Soldering Temperature (5 sec)	240°C
IR EMITTER	
Power Dissipation	100 mW (1)
Reverse Voltage	3 V
Continuous Forward Current	50 mA
DETECTOR	
Supply Voltage	12 V (2)
Output Sink Current	18 mA
Duration of Output	
Short to V_{CC} or Ground	1.0 sec.

Notes
1. Derate linearly at 0.78 mW/°C above 25°C.
2. Derate linearly from 25°C to 5.5 V at 70°C.

SCHEMATIC



Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

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SWITCHING WAVEFORM

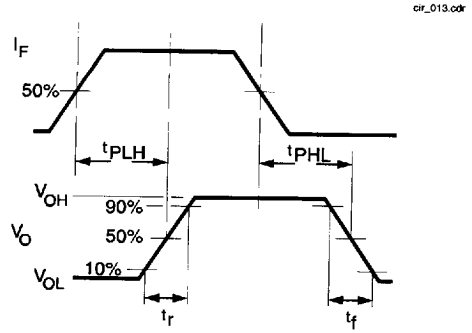


Fig. 1 IRED Forward Bias Characteristics

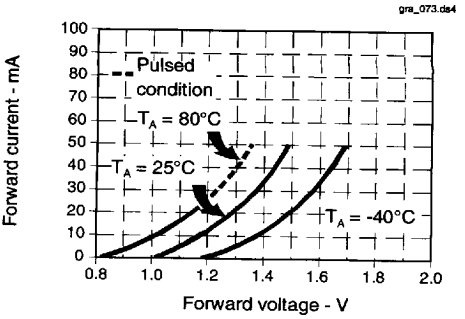
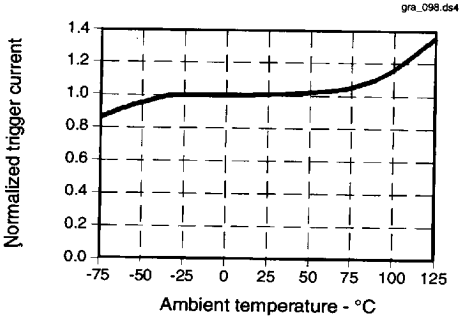


Fig. 2 IRED Trigger Current vs Temperature



All Performance Curves Show Typical Values

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